

Small Signal Diode

1N4149



**AXIAL LEAD
(DO-35)
CASE 017AG**
(Color Band Denotes Cathode)

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted) (Notes 1, 2, 3)

| Symbol | Rating | Value | Unit |
|-------------|---|-------------|------------------|
| V_{RRM} | Maximum Repetitive Reverse Voltage | 100 | V |
| $I_{F(AV)}$ | Average Rectified Forward Current | 500 | mA |
| I_{FSM} | Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 s Pulse Width = 1.0 μs | 1.0 4.0 | A |
| T_{STG} | Storage Temperature Range | -65 to +200 | $^\circ\text{C}$ |
| T_J | Operating Junction Temperature | 175 | $^\circ\text{C}$ |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- These ratings are limiting values above which the serviceability of the diode may be impaired.
- These ratings are based on a maximum junction temperature of 200°C .
- These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

THERMAL CHARACTERISTICS

| Symbol | Parameter | Max | Unit |
|-----------------|---|-----|------------------|
| P_D | Power Dissipation | 500 | mW |
| $R_{\theta JA}$ | Thermal Resistance, Junction-to-Ambient | 300 | $^\circ\text{C}$ |

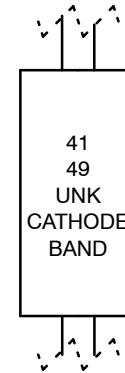
ELECTRICAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| Symbol | Parameter | Conditions | Min | Max | Unit |
|----------|-----------------------|---|-----------|----------|---------------------|
| V_R | Breakdown Voltage | $I_R = 5 \mu\text{A}$ $I_R = 100 \mu\text{A}$ | 75 100 | - - | V |
| V_F | Forward Voltage | $I_F = 10 \text{ mA}$ | - | 1.0 | V |
| I_R | Reverse Leakage | $V_R = 20 \text{ V}$ $V_R = 20 \text{ V}, T_A = 150^\circ\text{C}$ | - - | 25 50 | nA μA |
| C_T | Total Capacitance | $V_R = 0, f = 1.0 \text{ MHz}$ | - | 2 | pF |
| t_{rr} | Reverse Recovery Time | $I_F = 10 \text{ mA}, V_R = 6.0 \text{ V}$ $I_{rr} = 1 \text{ mA}, R_L = 100 \Omega$ | - | 4 | ns |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

MARKING DIAGRAM



4149 = Specific Device Code

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|----------|--------------------|-------------------------------|
| 1N4149 | DO-35 (Pb-Free) | 5,000 Units / Bulk |
| 1N4149TR | DO-35 (Pb-Free) | 10,000 Units / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

TYPICAL PERFORMANCE CHARACTERISTICS

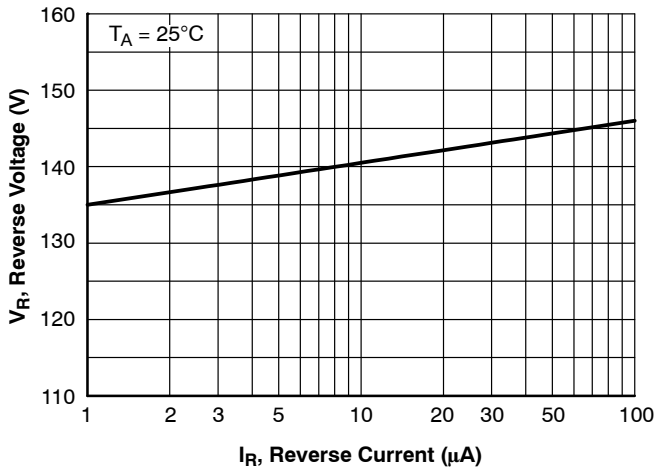


Figure 1. Reverse Voltage vs. Reverse Current
 $B_V - 1.0$ to $100 \mu A$

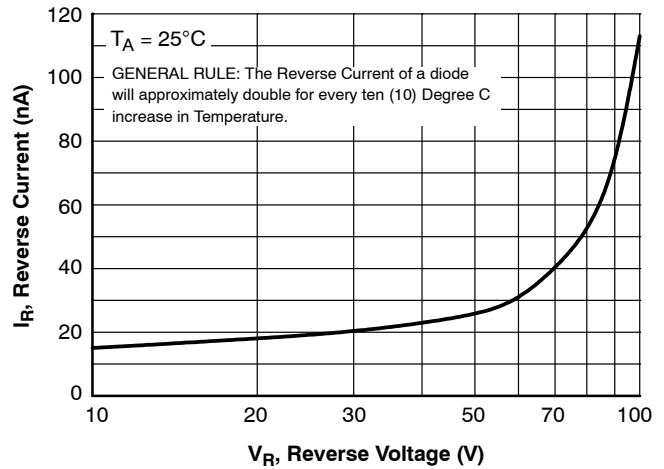


Figure 2. Reverse Current vs. Reverse Voltage
 $I_R - 10$ to $100 V$

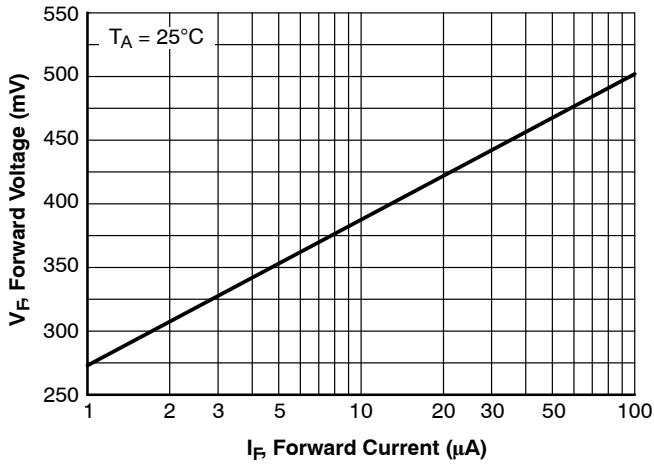


Figure 3. Forward Voltage vs. Forward Current
 $V_F - 1.0$ to $100 \mu A$

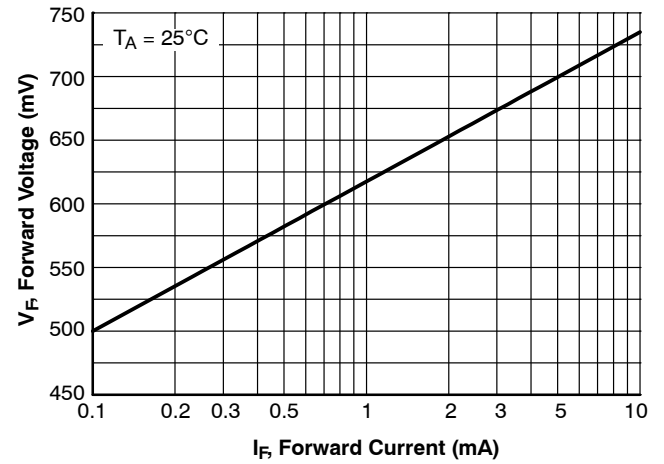


Figure 4. Forward Voltage vs. Forward Current
 $V_F - 0.1$ to $10 mA$

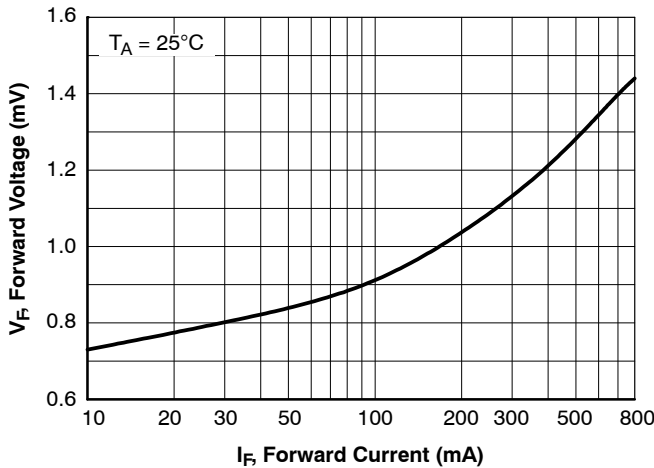


Figure 5. Forward Voltage vs. Forward Current
 $V_F - 10$ to $800 mA$

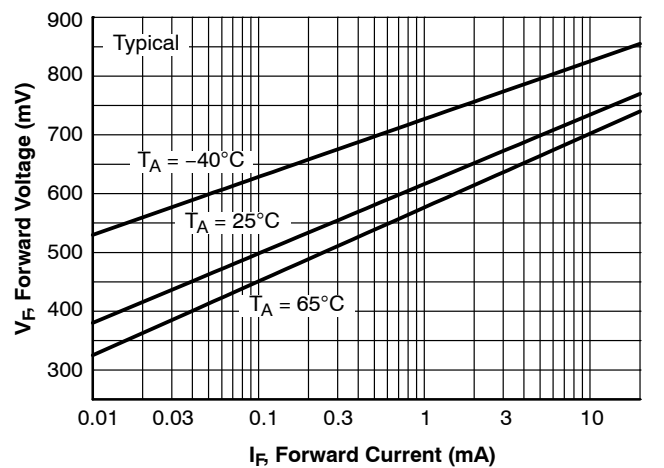


Figure 6. Forward Voltage vs. Ambient Temperature, $V_F - 0.01$ to $20 mA (-40$ to $+65^\circ C)$

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

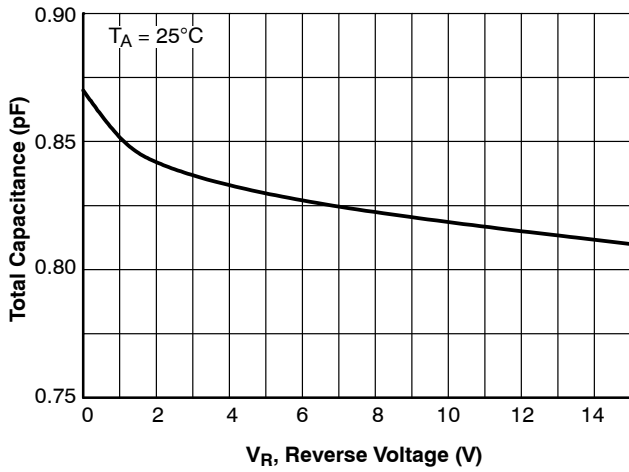


Figure 7. Total Capacitance

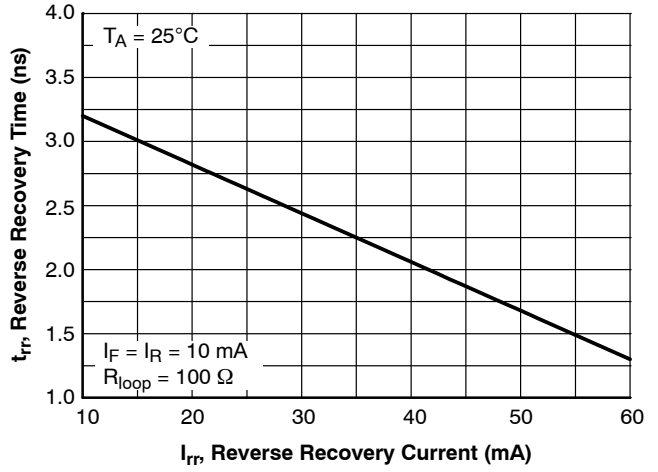


Figure 8. Reverse Recovery Time vs. Reverse Recovery Current

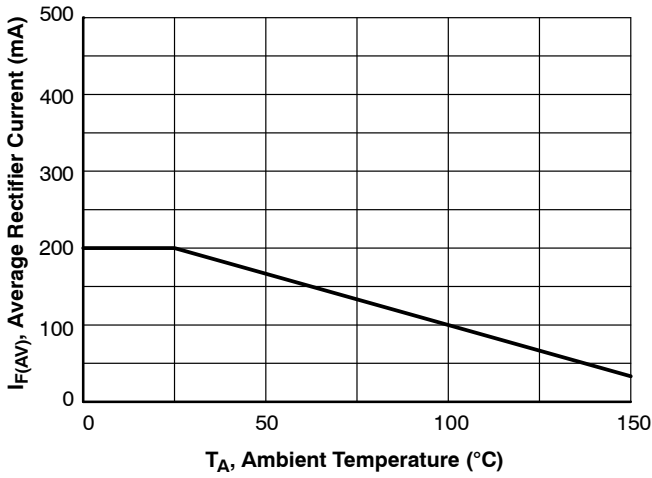


Figure 9. Average Rectified Current ($I_{F(AV)}$) vs. Ambient Temperature (T_A)

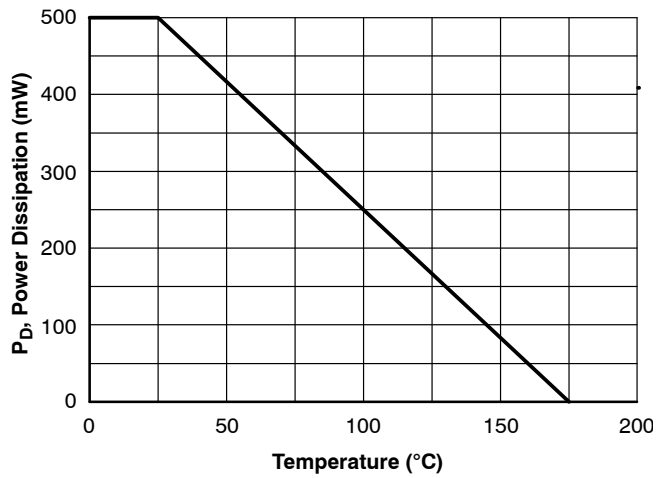
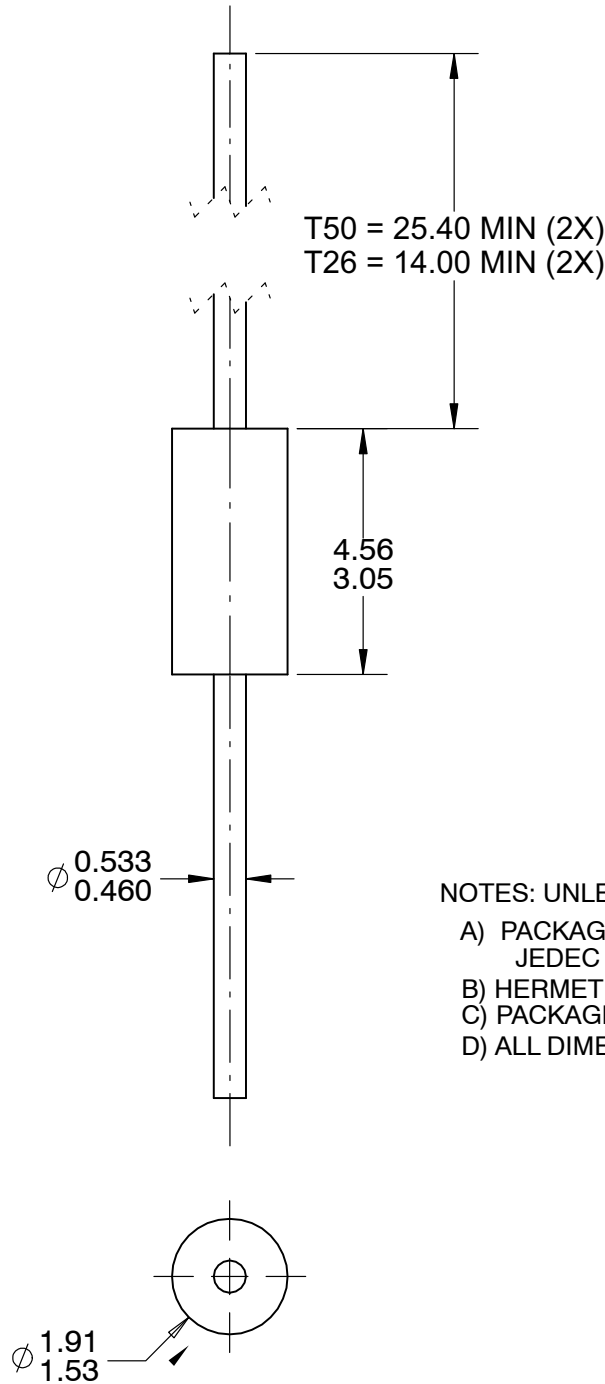


Figure 10. Power Derating Curve


AXIAL LEAD
CASE 017AG
ISSUE 0

DATE 31 AUG 2016



- NOTES: UNLESS OTHERWISE SPECIFIED
- A) PACKAGE STANDARD REFERENCE: JEDEC DO-204, VARIATION AH.
 - B) HERMETICALLY SEALED GLASS PACKAGE.
 - C) PACKAGE WEIGHT IS 0.137 GRAM.
 - D) ALL DIMENSIONS ARE IN MILLIMETERS.

| | | |
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